**Vishay Semiconductors** 

### **Power SMD LED PLCC-4**

#### **FEATURES**

- Utilizing AlInGaP technology
- · Available in 8 mm tape
- · Luminous intensity, color and forward voltage categorized per packing unit
- · Luminous intensity ratio per packing unit  $I_{Vmax}/I_{Vmin} \le 1.6$
- ESD class 2
- · Suitable for all soldering methods according to CECC
- Lead (Pb)-free device

#### **APPLICATIONS**

- Traffic Signals and Signs
- Interior and exterior lighting
- Dashboard illumination
- · Indicator and backlighting purposes for audio, video, LCDs switches, symbols, illuminated advertising etc.

PARTS TABLE		
PART	COLOR, LUMINOUS INTENSITY	DOMINANT WAVELENGTH
TLMK3200	Red, I <sub>V</sub> > 200 mcd (typ. 500 mcd)	611 nm to 622 nm
TLMK3201	Red, I <sub>V</sub> = (250 to 800) mcd	611 nm to 622 nm
TLMK3202	Red, I <sub>V</sub> = (320 to 800) mcd	611 nm to 622 nm
TLMK3203	Red, I <sub>V</sub> = (400 to 1250) mcd	611 nm to 622 nm
TLMS3200	Red, I <sub>V</sub> > 160 mcd (typ. 300 mcd)	626 nm to 638 nm
TLMS3201	Red, I <sub>V</sub> = (160 to 400) mcd	626 nm to 638 nm
TLMS3202	Red, I <sub>V</sub> = (250 to 800) mcd	626 nm to 638 nm
TLMO3200	Soft orange, I <sub>V</sub> > 200 mcd (typ. 500 mcd)	600 nm to 611 nm
TLMO3201	Soft orange, I <sub>V</sub> = (250 to 800) mcd	600 nm to 611 nm
TLMO3202	Soft orange, I <sub>V</sub> = (320 to 800) mcd	600 nm to 611 nm
TLMO3203	Soft orange, I <sub>V</sub> = (400 to 1250) mcd	600 nm to 611 nm
TLMY3200	Yellow, I <sub>V</sub> > 200 mcd (typ. 450 mcd)	583 nm to 594 nm
TLMY3201	Yellow, I <sub>V</sub> = (250 to 800) mcd	583 nm to 594 nm
TLMY3202	Yellow, I <sub>V</sub> = (320 to 800) mcd	583 nm to 594 nm
TLMY3203	Yellow, I <sub>V</sub> = (400 to 1250) mcd	583 nm to 594 nm









#### DESCRIPTION

The TLM.32.. series is an advanced development in terms of heat dissipation.

The leadframe profile of this PLCC-3 SMD package is optimized to reduce the thermal resistance.

This allows higher drive current and doubles the light output compared to Vishay's high intensity SMD LED in PLCC-2 package.

#### **PRODUCT GROUP AND PACKAGE DATA**

- Product group: LED
- Package: SMD PLCC-4
- Product series: power

DADTS TABLE

Angle of half intensity: ± 60°

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ABSOLUTE MAXIMUM RATINGS <sup>1)</sup> TLMK32, TLMS32, TLMO32, TLMY32							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage		V <sub>R</sub>	5	V			
Forward current		١ <sub>F</sub>	70	mA			
Power dissipation	$\begin{split} \text{T}_{amb} &\leq 65 \ ^{\circ}\text{C} \ (290 \ \text{K/W}), \\ \text{T}_{amb} &\leq 70 \ ^{\circ}\text{C} \ (270 \ \text{K/W}) \end{split}$	P <sub>tot</sub>	180	mW			
Junction temperature		Тj	125	°C			
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C			
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C			
Thermal resistance junction/	mounted on PC board FR4 optional paddesign (see page 11)	R <sub>thJA</sub>	290	K/W			
ambient	mounted on PC board FR4 recommended paddesign (see page 10)	R <sub>thJA</sub>	270	K/W			

Note: <sup>1)</sup>  $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> TLMK32, RED							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
		TLMK3200	Ι <sub>V</sub>	200	500		mcd
Luminous intensity	I <sub>F</sub> = 50 mA	TLMK3201	Ι <sub>V</sub>	250		800	mcd
Luminous intensity	IF = 50 IIIA	TLMK3202	Ι <sub>V</sub>	320		800	mcd
		TLMK3203	Ι <sub>V</sub>	400		1250	mcd
Luminous flux/Luminous intensity			$\phi_V/I_V$		3		mlm/mcd
Dominant wavelength	I <sub>F</sub> = 50 mA		λ <sub>d</sub>	611	617	622	nm
Peak wavelength	I <sub>F</sub> = 50 mA		λ <sub>p</sub>		624		nm
Spectral bandwidth at 50 % I <sub>rel max</sub>	I <sub>F</sub> = 50 mA		Δλ		18		nm
Angle of half intensity	I <sub>F</sub> = 50 mA		φ		± 60		deg
Forward voltage	I <sub>F</sub> = 50 mA		V <sub>F</sub>	1.85	2.1	2.55	V
Reverse current	V <sub>R</sub> = 5 V		V <sub>R</sub>		0.01	10	μA

Note: <sup>1)</sup>  $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> TLMS32, RED							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
		TLMS3200	Ι <sub>V</sub>	160	300		mcd
Luminous intensity	I <sub>F</sub> = 50 mA	TLMS3201	Ι <sub>V</sub>	160		400	mcd
		TLMS3202	Ι <sub>V</sub>	250		800	mcd
Luminous flux/Luminous intensity			$\phi_V/I_V$		3		mlm/mcd
Dominant wavelength	I <sub>F</sub> = 50 mA		$\lambda_d$	626	630	638	nm
Peak wavelength	I <sub>F</sub> = 50 mA		λ <sub>p</sub>		641		nm
Spectral bandwidth at 50 % I <sub>rel max</sub>	I <sub>F</sub> = 50 mA		Δλ		17		nm
Angle of half intensity	I <sub>F</sub> = 50 mA		φ		± 60		deg
Forward voltage	I <sub>F</sub> = 50 mA		V <sub>F</sub>	1.85	2.1	2.55	V
Reverse current	V <sub>R</sub> = 5 V		V <sub>R</sub>		0.01	10	μΑ

Note: <sup>1)</sup>  $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified



OPTICAL AND ELECT	<b>FRICAL CHARACTE</b>	RISTICS <sup>1</sup>	<sup>)</sup> TLMO32	2, SOFT	ORANG	E	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
		TLMO3200	Ι <sub>V</sub>	200	500		mcd
Luminous intensity	I <sub>F</sub> = 50 mA	TLMO3201	Ι <sub>V</sub>	250		800	mcd
Luminous intensity	1F = 30 111A	TLMO3202	Ι <sub>V</sub>	320		800	mcd
		TLMO3203	Ι <sub>V</sub>	400		1250	mcd
Luminous flux/Luminous intensity			φ <sub>V</sub> /I <sub>V</sub>		3		mlm/mcd
Dominant wavelength	I <sub>F</sub> = 50 mA		$\lambda_d$	600	605	611	nm
Peak wavelength	I <sub>F</sub> = 50 mA		λ <sub>p</sub>		611		nm
Spectral bandwidth at 50 % I <sub>rel max</sub>	I <sub>F</sub> = 50 mA		Δλ		17		nm
Angle of half intensity	I <sub>F</sub> = 50 mA		φ		± 60		deg
Forward voltage	I <sub>F</sub> = 50 mA		V <sub>F</sub>	1.85	2.1	2.55	V
Reverse current	V <sub>R</sub> = 5 V		V <sub>R</sub>		0.01	10	μΑ

Note:

<sup>(1)</sup>  $T_{amb} = 25$  °C, unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS <sup>1)</sup> TLMY32, YELLOW							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
		TLMY3200	Ι <sub>V</sub>	200	450		mcd
Luminous intensity	I <sub>F</sub> = 50 mA	TLMY3201	Ι <sub>V</sub>	250		800	mcd
Luminous intensity	IF = 30 IIIA	TLMY3202	Ι <sub>V</sub>	320		800	mcd
		TLMY3203	Ι <sub>V</sub>	400		1250	mcd
Luminous flux/Luminous intensity			$\phi_V/I_V$		3		mlm/mcd
Dominant wavelength	I <sub>F</sub> = 50 mA		$\lambda_d$	583	588	594	nm
Peak wavelength	I <sub>F</sub> = 50 mA		λ <sub>p</sub>		590		nm
Spectral bandwidth at 50 % I <sub>rel max</sub>	I <sub>F</sub> = 50 mA		Δλ		18		nm
Angle of half intensity	I <sub>F</sub> = 50 mA		φ		± 60		deg
Forward voltage	I <sub>F</sub> = 50 mA		V <sub>F</sub>	1.85	2.1	2.55	V
Reverse current	V <sub>R</sub> = 5 V		V <sub>R</sub>		0.01	10	μA

Note: <sup>1)</sup>  $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

FORWARD VOLTAGE CLASSIFICATION					
GROUP	FORWARD VOLTAGE (V)				
GROOP	MIN	МАХ			
1	1.85	2.25			
2	2.15	2.55			

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#### **COLOR CLASSIFICATION**

	DOMINANT WAVELENGTH (NM)						
GROUP	RI	ED	SOFT 0	RANGE	YELL	.OW	
	MIN	MIN	MAX	MIN	МАХ	MAX	
1	611	618	598	601	581	584	
2	614	622	600	603	583	586	
3			602	605	585	588	
4			604	607	587	590	
5			606	609	589	592	
6			608	611	591	594	

#### LUMINOUS INTENSITY CLASSIFICATION

GROUP	LUMINOUS INTENSITY (MCD)				
GROOP	MIN	МАХ			
Ха	160	250			
Xb	200	320			
Ya	250	400			
Yb	320	500			
Za	400	630			
Zb	500	800			
Oa	630	1000			
Ob	800	1250			

GROUP NAME ON LABEL							
LUMINOUS INTENSITY GROUP	HALFGROUP	WAVELENGTH	FORWARD VOLTAGE				
Z	b	2	1				

One packing unit/tape contains only one classification group of luminous intensity, color and forward voltage. Only one single classification groups is not available.

The given groups are not order codes, customer specific group combinations require marketing agreement. No color subgrouping for Super Red.

#### **TYPICAL CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

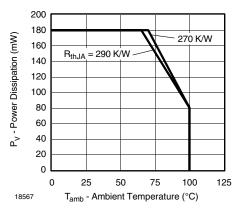


Figure 1. Power Dissipation vs. Ambient Temperature

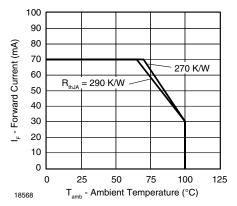


Figure 2. Forward Current vs. Ambient Temperature

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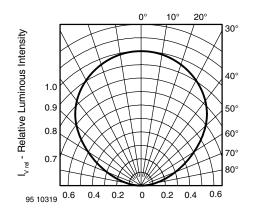


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

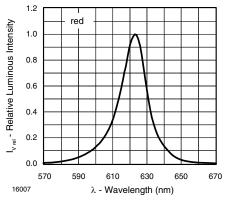


Figure 4. Relative Intensity vs. Wavelength

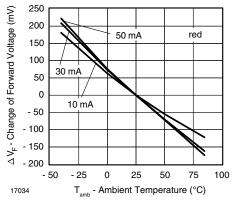


Figure 5. Change of Forward Voltage vs. Ambient Temperature

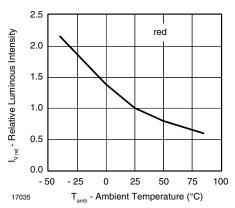


Figure 6. Relative Luminous Intensity vs. Amb. Temperature

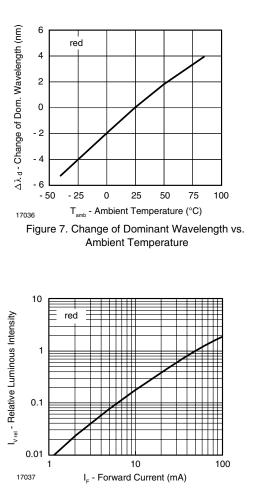


Figure 8. Relative Luminous Intensity vs. Forward Current

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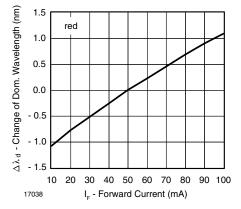


Figure 9. Change of Dominant Wavelength vs. Forward Current

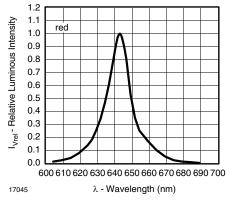


Figure 10. Relative Intensity vs. Wavelength

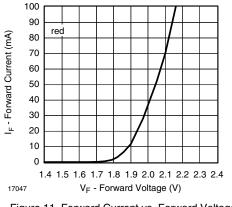


Figure 11. Forward Current vs. Forward Voltage

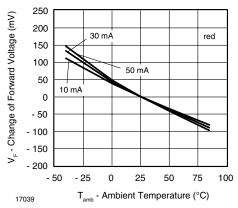


Figure 12. Change of Forward Voltage vs. Ambient Temperature

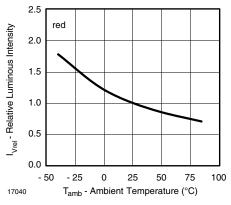


Figure 13. Relative Luminous Intensity vs. Amb. Temperature

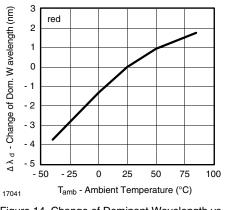


Figure 14. Change of Dominant Wavelength vs. **Ambient Temperature** 



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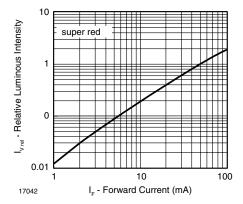


Figure 15. Relative Luminous Intensity vs. Forward Current

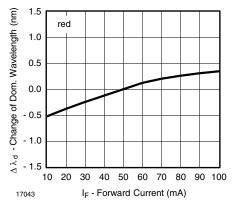
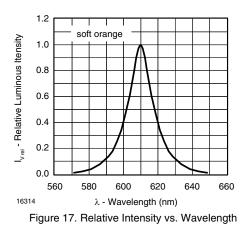


Figure 16. Change of Dominant Wavelength vs. Forward Current



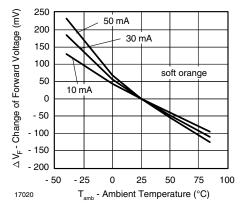


Figure 18. Change of Forward Voltage vs. Ambient Temperature

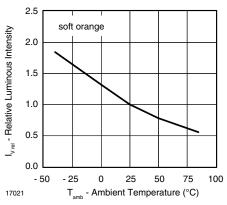


Figure 19. Relative Luminous Intensity vs. Amb. Temperature

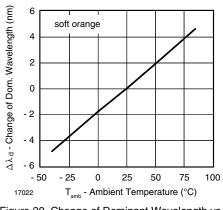


Figure 20. Change of Dominant Wavelength vs. Ambient Temperature

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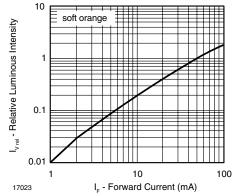


Figure 21. Relative Luminous Intensity vs. Forward Current

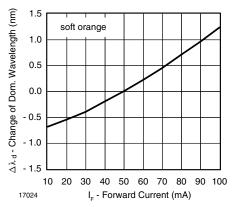


Figure 22. Change of Dominant Wavelength vs. Forward Current

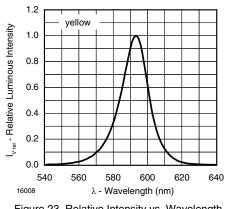


Figure 23. Relative Intensity vs. Wavelength

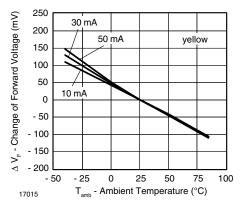


Figure 24. Change of Forward Voltage vs. Ambient Temperature

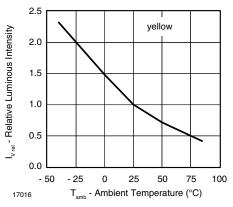
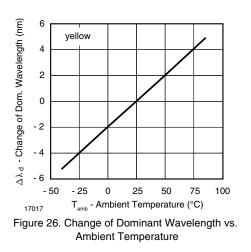


Figure 25. Relative Luminous Intensity vs. Amb. Temperature





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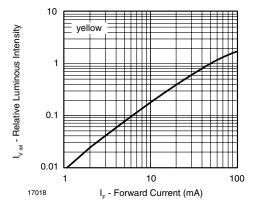


Figure 27. Relative Luminous Intensity vs. Forward Current

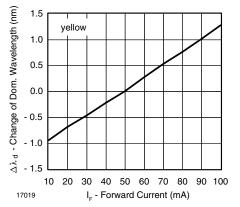
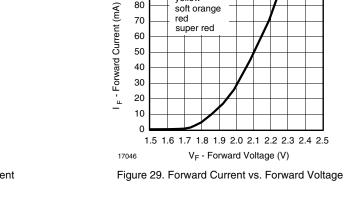


Figure 28. Change of Dominant Wavelength vs. Forward Current



100 90

80

70

60 50 yellow

soft orange red

super red

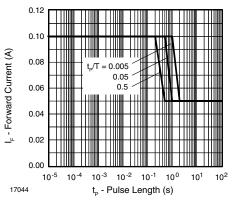
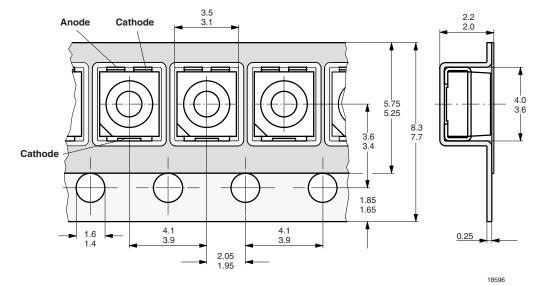


Figure 30. Forward Current vs. Pulse Length

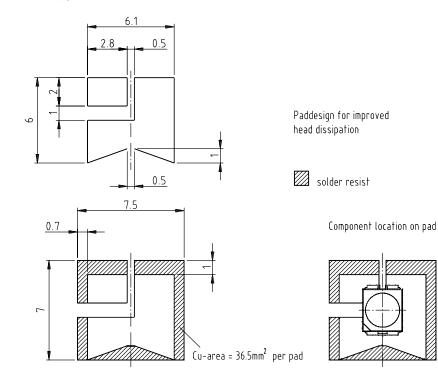


**TAPING** in millimeters

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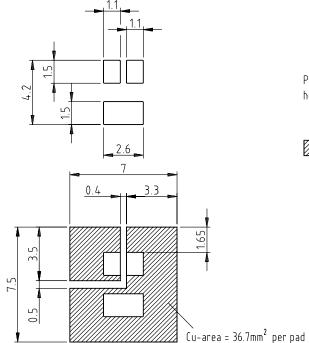
#### **RECOMMENDED PAD DESIGN** in millimeters

(Wave-Soldering),  $R_{thJA} = 270 \text{ K/W}$ 



#### **RECOMMENDED PAD DESIGN** in millimeters

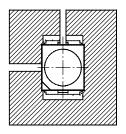
(Reflow-Soldering), R<sub>thJA</sub> = 270 K/W



Paddesign for improved head dissipation

solder resist

Component location on pad



16261

16260

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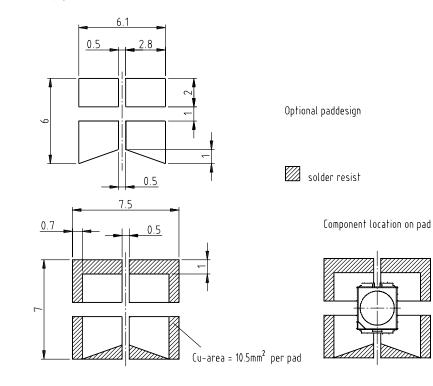






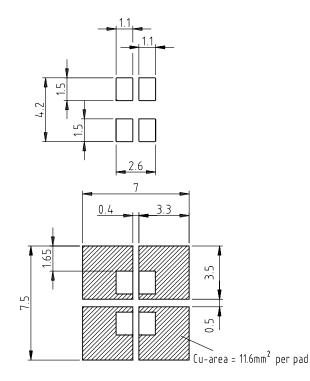
#### **OPTIONAL PAD DESIGN** in millimeters

(Wave-Soldering), R<sub>thJA</sub> = 290 K/W



#### **OPTIONAL PAD DESIGN** in millimeters

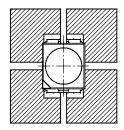
(Reflow-Soldering), R<sub>thJA</sub> = 290 K/W



Optional paddesign

solder resist

Component location on pad

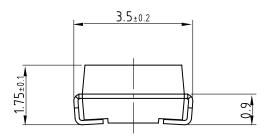


16263

16262

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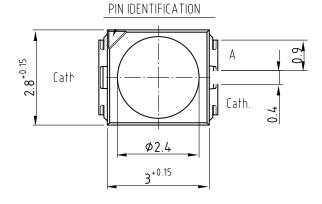
#### **PACKAGE DIMENSIONS** in millimeters

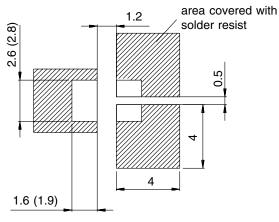




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#### **Mounting Pad Layout**





Dimensions: IR and Vaporphase (Wave Soldering)

Drawing-No. : 6.541-5054.01-4 Issue: 2; 02.12.05

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#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

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# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.